L Number	Hits	Search Text	DB	Time stamp
9	0	(semiconductor near fiber) and (ball near2 lens) and	USPAT;	2003/04/09 11:19
		(oxidi\$4 near aluminium)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
16	2	(semiconductor near fiber) and (ball near2 lens) and	USPAT;	2003/04/09 11:20
		((fabry near perot) or fp) and (DFB or (distributed	US-PGPUB;	
		near feed near back))	EPO; JPO;	
		1	DERWENT;	
			IBM TDB	
-	1	(semiconductor near laser) and shaper and (oxidi\$4	USPAT;	2003/04/08 07:22
		near aluminium)	US-PGPUB;	
			EPO; JPO;	
		. '	DERWENT;	
			IBM TDB	
_	1	(semiconductor near laser) and shaper and (oxidi\$4	USPAT;	2003/04/08 08:20
_	'	near aluminium)	US-PGPUB;	2000/04/00 00:20
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	0.5	(annian advates and Inner) and Invidit A ages		2002/04/09 09:02
-	85	(semiconductor near laser) and (oxidi\$4 near	USPAT;	2003/04/08 08:02
		aluminium)	US-PGPUB;	
		'	EPO; JPO;	
		. •	DERWENT;	
	4.0		IBM_TDB	0000/04/00 00 00
-	13	((semiconductor near laser) and (oxidi\$4 near	USPAT;	2003/04/08 08:02
		aluminium)) and optical near fiber	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	25	((semiconductor near laser) and (oxidi\$4 near	USPAT;	2003/04/08 09:43
		aluminium)) and fiber	US-PGPUB;	
		·	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	23	(semiconductor near laser) and shape and (oxidi\$4	USPAT;	2003/04/08 08:22
		near aluminium)	US-PGPUB;	
}			EPO; JPO;	
.			DERWENT;	
			IBM_TDB	
-	10	((semiconductor near laser) and shape and (oxidi\$4	USPAT;	2003/04/08 08:23
		near aluminium)) and fiber	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	2	(semiconductor near laser) and (beam near shape)	USPAT;	2003/04/08 08:22
		and (oxidi\$4 near aluminium)	US-PGPUB;	
		*	EPO; JPO;	
			DERWENT;	
		·	IBM TDB	
-	12	(((semiconductor near laser) and (oxidi\$4 near	USPAT;	2003/04/08 09:35
		aluminium)) and fiber) and lens	US-PGPUB;	
		a.c	EPO; JPO;	
			DERWENT;	
			IBM TDB	
			I IDIVI I DD	

	286	(semiconductor near laser) and (mirror near (concave	USPAT;	2003/04/08 09:45
	200	or convex)) and fiber	US-PGPUB;	
		, i i i i i i i i i i i i i i i i i i i	EPO; JPO;	
			DERWENT;	
		,	IBM TDB	
_	22	(semiconductor near laser) and (mirror near	USPAT;	2003/04/08 09:49
		aluminium) and fiber	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	7	((semiconductor near laser) and (mirror near	USPAT;	2003/04/08 09:46
	_	aluminium) and fiber) and ((semiconductor near laser)	US-PGPUB;	
		and (mirror near (concave or convex)) and fiber)	EPO; JPO;	
		Constitution of the consti	DERWENT;	
			IBM TDB	
<u>-</u>	o	(semiconductor near laser) and (lens near aluminium)	USPAT;	2003/04/08 09:49
	Ĭ	and fiber	US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
			IBM TDB	
_	1	(semiconductor near laser) and (lens near aluminium)	USPAT;	2003/04/08 09:51
-	1	(Settiliconductor freat laser) and fields freat additionally	US-PGPUB;	2000/04/00 00:01
			EPO; JPO;	
			DERWENT;	
		·	IBM TDB	
	62	(semiconductor near laser) and (shap\$3 near2	USPAT;	2003/04/08 10:07
-	02	aluminium)	US-PGPUB;	2003/04/08 10.07
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	25	(semiconductor near laser) and (shap\$3 near	USPAT;	2003/04/08 09:58
-	25	aluminium)	US-PGPUB;	2003/04/00 03.30
			EPO; JPO;	
			DERWENT;	
	1		IBM TDB	
	26	(semiconductor near laser) and ((shap\$3 or lens)	USPAT;	2003/04/08 09:59
-	20	near aluminium)	US-PGPUB;	2000/04/00 00:55
		tied diuminium/	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	72	(semiconductor near laser) and ((shap\$3 or lens)	USPAT;	2003/04/08 10:12
-	'2	near2 aluminium)	US-PGPUB;	2000,04,00 10.12
		incare arunninum	EPO; JPO;	
			DERWENT;	
	1	4	IBM TDB	
	485	(semiconductor near laser) and ((shap\$3 or lens)	USPAT;	2003/04/08 10:13
-	405	WITH aluminium)	US-PGPUB;	
		vviii aunimuni,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
	112	(semiconductor near laser) and ((shap\$3 or lens)	USPAT;	2003/04/08 10:14
_	112	WITH aluminium) and (trench or groove)	US-PGPUB;	2000,04,00 10.14
		with auminium and thench of gloove)	EPO; JPO;	
			DERWENT;	
			IBM TDB	
	. 24	(comiconductor page large) and (labore 2 or large)	USPAT;	2003/04/08 10:44
-	34	(semiconductor near laser) and ((shap\$3 or lens)	ř ·	2003/04/00 10.44
		WITH aluminium) and (trench or groove) AND	US-PGPUB;	
	1	FIBER	EPO; JPO;	
			DERWENT;	
ł	1		IBM_TDB	

-	1864	(semiconductor near laser) and (shap\$3 or lens) and (trench or groove) AND FIBER	USPAT; US-PGPUB;	2003/04/08 10:46
		-	EPO; JPO; DERWENT;	
			IBM TDB	
	660	((semiconductor near laser) and (shap\$3 or lens) and	USPAT;	2003/04/08 10:46
-	000	(trench or groove) AND FIBER) AND 372/\$	US-PGPUB;	2000/04/00 10:40
		(tiench of gloove) AND FIBER! AND 37219	EPO; JPO;	
			DERWENT;	
			IBM_TDB	0000/04/00 44 00
-	594	((semiconductor near laser) and (shap\$3 or lens) and	USPAT;	2003/04/08 14:29
		(trench or groove) AND FIBER) AND aluminium	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	43	(((semiconductor near laser) and (shap\$3 or lens)	USPAT;	2003/04/08 11:24
		and (trench or groove) AND FIBER) AND aluminium)	US-PGPUB;	
		and ((fabry near perot) or fp) and (DFB or (distributed	EPO; JPO;	
		near feed near back))	DERWENT;	
			IBM TDB	
-	79	((semiconductor near laser) and (shap\$3 or lens) and	USPAT;	2003/04/08 14:30
		(trench or groove) AND FIBER) AND aluminium near	US-PGPUB;	
		oxid\$4	EPO; JPO;	
			DERWENT;	
			IBM TDB	
· _	6	(((semiconductor near laser) and (shap\$3 or lens)	USPAT;	2003/04/08 14:30
	١	and (trench or groove) AND FIBER) AND aluminium	US-PGPUB;	2000,01,0011100
		near oxid\$4) and ((((semiconductor near laser) and	EPO; JPO;	
		(shap\$3 or lens) and (trench or groove) AND FIBER)	DERWENT;	
		AND aluminium) and ((fabry near perot) or fp) and	IBM TDB	
		(DFB or (distributed near feed near back)))	15141_155	
	193	(semiconductor near laser) and (ball near2 lens)	USPAT;	2003/04/08 15:29
_	193	(Serificonductor flear laser) and (ball flear 2 letts)	US-PGPUB;	2003/04/00 13:23
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
1	1112	lossisseduates and lossy and lossy as lossy	USPAT;	2003/04/08 15:18
-	1113	(semiconductor near laser) and (convex or (convex	'	2003/04/00 15.10
		near (mirror or lens))) and (optical near element)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(Included the particular of th	IBM_TDB	2002/04/09 15:10
-	0	(semiconductor near laser) and ((convex or concave)	USPAT;	2003/04/08 15:19
		near beam near shaper)	US-PGPUB;	
			EPO; JPO;	
		·	DERWENT;	
			IBM_TDB	0000/04/00 == ==
-	20	((semiconductor near laser) and (convex or (convex	USPAT;	2003/04/08 15:28
		near (mirror or lens))) and (optical near element)) and	US-PGPUB;	
		((semiconductor near laser) and (ball near2 lens))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1	((semiconductor near laser) and (convex or (convex	USPAT;	2003/04/08 15:29
		near (mirror or lens))) and (optical near element)) and	US-PGPUB;	
		((semiconductor near laser) and (ball near2 lens)) and	EPO; JPO;	
		372/92	DERWENT;	
		<u> </u>	IBM_TDB	

-	0	((semiconductor near laser) and (convex or (convex	USPAT;	2003/04/08 15:28
		near (mirror or lens))) and (optical near element)) and	US-PGPUB;	
		((semiconductor near laser) and (ball near2 lens)) and	EPO; JPO;	
		372/99	DERWENT;	
i		,	IBM_TDB	
-	0	((semiconductor near laser) and (convex or (convex	USPAT;	2003/04/08 15:29
		near (mirror or lens))) and (optical near element)) and	US-PGPUB;	
		((semiconductor near laser) and (ball near2 lens)) and	EPO; JPO;	
		372/6	DERWENT;	
-			IBM_TDB	
-	16	(semiconductor near fiber) and (ball near2 lens)	USPAT;	2003/04/09 10:42
			US-PGPUB;	
		·	EPO; JPO;	
			DERWENT;	
			IBM TDB	